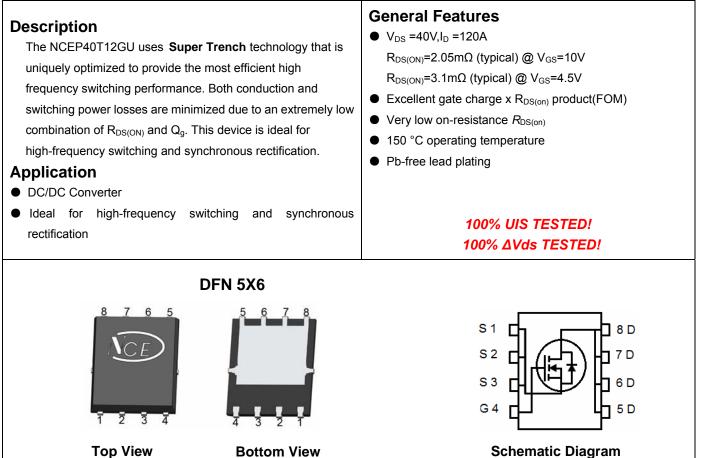


# NCE N-Channel Super Trench Power MOSFET



**Schematic Diagram** 

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P40T12GU	NCEP40T12GU	DFN5X6-8L	-	-	-

### Absolute Maximum Ratings (T<sub>c</sub>=25<sup>°</sup>Cunless otherwise noted)

**Bottom View** 

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	40	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous (Silicon Limited)	Ι <sub>D</sub>	120	А	
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	84.8	Α	
Pulsed Drain Current (Package Limited)	I <sub>DM</sub>	400	Α	
Maximum Power Dissipation	PD	120	W	
Derating factor		0.96	W/℃	
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	480	mJ	
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	°C	
Thermal Characteristic				
Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	R <sub>θJC</sub>	1.04	°C/W	



# Electrical Characteristics (Tc=25 $^\circ\!\!\mathrm{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•	•		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	40		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V	-	-	±100	nA
On Characteristics (Note 3)			•	•		
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_D=250\mu A$	1.2	1.7	2.2	V
Drain-Source On-State Resistance	В	$V_{GS}$ =10V, $I_{D}$ =60A	-	2.05	2.35	mΩ
	R <sub>DS(ON)</sub>	$V_{GS}$ =4.5V, I <sub>D</sub> =60A	-	3.1	3.6	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =60A		56	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	V <sub>DS</sub> =20V,V <sub>GS</sub> =0V,	-	2250	-	PF
Output Capacitance	C <sub>oss</sub>		-	815	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	43	-	PF
Switching Characteristics (Note 4)			•	•		
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =20V,I <sub>D</sub> =60A V <sub>GS</sub> =10V,R <sub>G</sub> =1.6Ω	-	9	-	nS
Turn-on Rise Time	tr		-	3.5	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	30	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	4	-	nS
Total Gate Charge	Qg	V <sub>DS</sub> =20V,I <sub>D</sub> =60A,	-	44		nC
Gate-Source Charge	Q <sub>gs</sub>		-	7.5		nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	7		nC
Drain-Source Diode Characteristics			•		•	<u>.</u>
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =60A	-		1.2	V
Diode Forward Current	I <sub>S</sub>		-	-	120	А
Reverse Recovery Time	t <sub>rr</sub>	$T_J$ = 25°C, $I_F$ = $I_S$	-		21	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-		60	nC

#### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

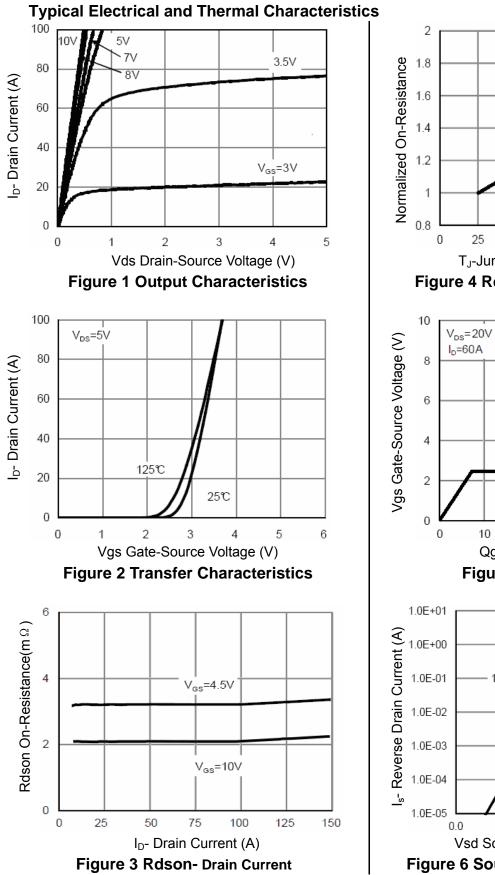
2. Surface Mounted on FR4 Board, t  $\leq$  10 sec.

3. Pulse Test: Pulse Width ≤ 300 $\mu$ s, Duty Cycle ≤ 2%.

4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25  $^\circ C$  ,V\_DD=20V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$ 





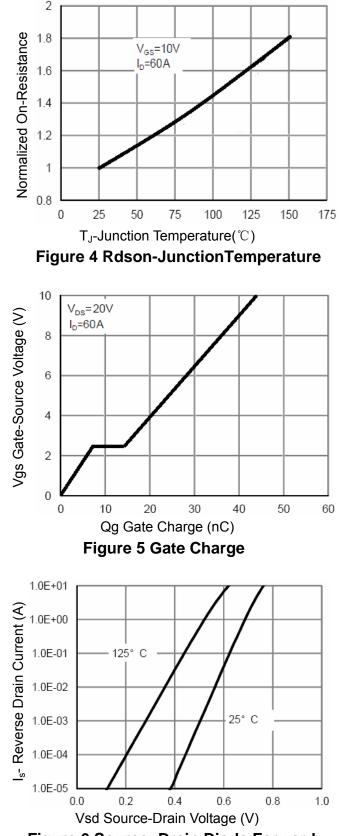


Figure 6 Source- Drain Diode Forward



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# NCEP40T12GU

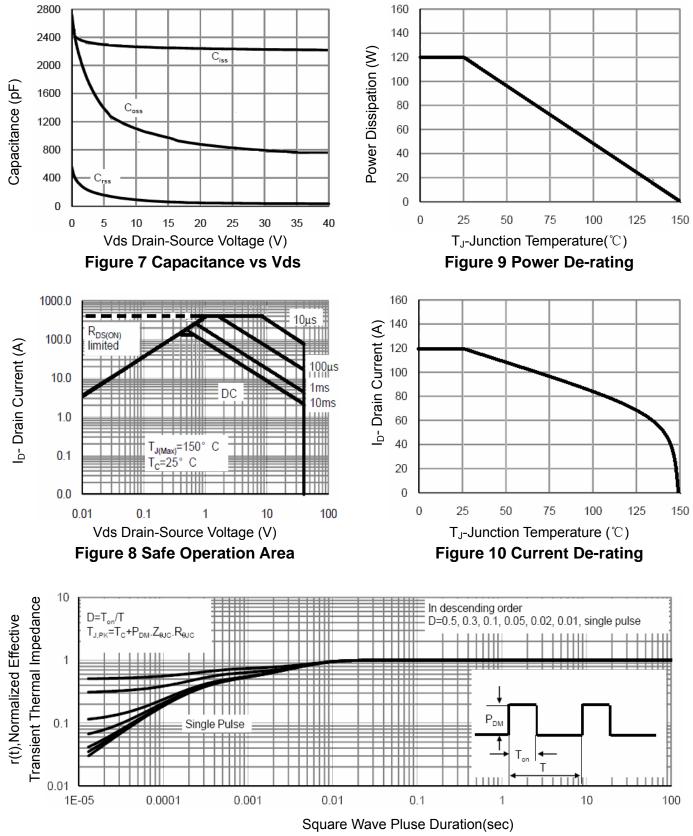
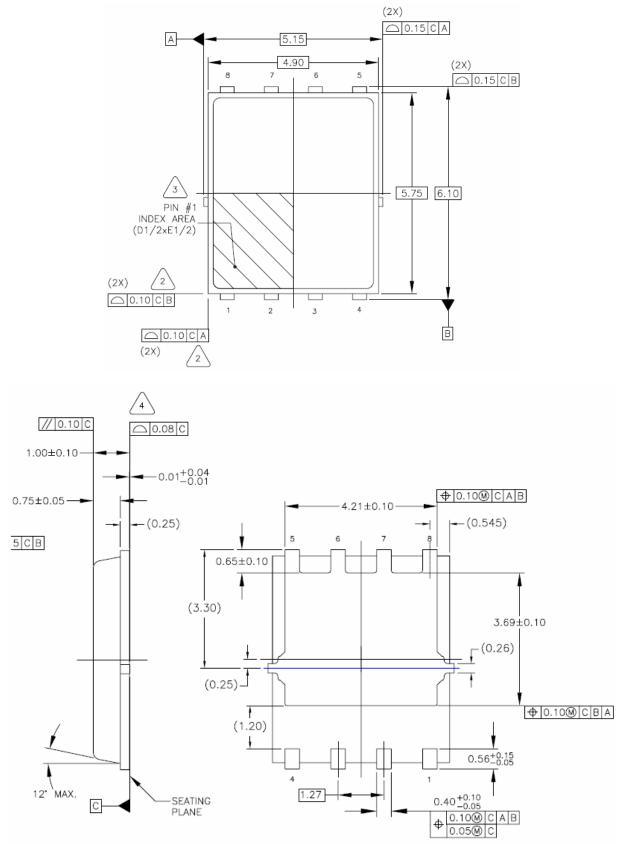


Figure 11 Normalized Maximum Transient Thermal Impedance



## DFN5X6-8L Package Information





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